Shell effects on hole-coupled electron transfer dynamics from CdSe/CdS quantum dots to methyl viologen†

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Electron transfer (ET) dynamics from the 1Se electron state in quasi-type II CdSe/CdS core/shell quantum dots (QDs) to adsorbed methyl viologen (MV2+) were measured using femtosecond transient absorption spectroscopy. The intrinsic ET rate kET was determined from the measured average number of ET-active MV2+ per QD, which permits reliable comparisons of variant shell thickness and different hole states. The 1Se electron was extracted efficiently from the CdSe core, even for CdS shells up to 20 Å thick. The ET rate decayed exponentially from 1010 to 109 s−1 for increasing CdS shell thicknesses with an attenuation factor β ≈ 0.13 Å−1. We observed that compared to the ground state exciton 1S1S3/2 the electron coupled to the 2S3/2 hot hole state exhibited slower ET rates for thin CdS shells. We attribute this behaviour to an Auger-assisted ET process (AAET), which depends on electron–hole coupling controlled by the CdS shell thickness.

1 Introduction

Since the initial study of semiconductor quantum dots (QDs),1–3 their optical properties have drawn significant attention, particularly in terms of their great potential for applications such as alternative solar cell materials.4–7 The core/shell heterostructure is promising for enhancing performance of solar cells8,9 and such structures have also been studied extensively for their attractive properties such as good photostability and high photoluminescence quantum yield (PL QY).9–14 Different types of core/shell QDs can be classified by the band-gap and the relative positions of the electronic energy levels of the involved semiconductor materials.11 In this paper we focus on the quasi-type II CdSe/CdS QDs, in which the excited electron is delocalized throughout the entire structure while the hole is localized in the core. The CdSe/CdS QDs are more photochemically stable than the corresponding bare core nanoparticles.10 Recently CdSe/CdS QDs were synthesized with high PL QY up to 95%,12–14 as a result of the passivation of surface defect states.15

In order to optimize photon to current conversion in QD-based solar cells, one can control charge separation processes by changing the shell thickness.16,17 Previous efforts have concentrated on 1Se electron transfer (ET) from QDs to adsorbed ligands. In nanoscale systems, the Auger process can play an important role due to the strong quantum confinement and high density of hole states. Recently, Auger-assisted electron transfer (AAET) processes have been invoked to account for ultrafast electron transfer dynamics, in which the transfer of the electron was coupled to excitation of the hole.18,19 The CdS shell in core/shell nanocrystals is expected to influence electron–hole coupling, and should affect the ET dynamics. However, shell effects on hole-coupled-1Se electron transfer dynamics between semiconductor nanocrystals and adsorbed electron acceptors such as MV2+ have not been studied to date.

One difficulty in studying ET dynamics in QD-ligand complexes is the presence of multiple ET pathways when multiple acceptors adsorb to each QD.20 It is necessary to account for the distribution of acceptor molecules and to determine the mean number of active acceptors per QD, noting that not all added quencher molecules will necessarily be adsorbed to the QDs and not all adsorbates will be active in accepting electrons. Morris-Cohen et al. proposed a strategy based on transient absorption (TA) spectroscopy, which permits an accurate measurement of the average number of ET-active electron acceptors adsorbed per QD from an analysis of the initial TA
bleach amplitude, and the intrinsic ET rate $k_{ET}$, which is the rate corresponding to only one ET-active MV$^{2+}$ per QD and is independent of electron acceptor concentration.\textsuperscript{21} This approach circumvents problems associated with the inaccurate estimation of the concentrations of QDs and the uncertainty in the titration of MV$^{2+}$ solutions. Furthermore, the effects of shell thickness on QD–MV$^{2+}$ binding can be eliminated from the experimentally determined populations of ET-active MV$^{2+}$.

Here we report a TA-based study of the effects of the CdS shell thickness on the dynamics of 1Se electron transfer in quasi-type II CdSe/CdS QDs with adsorbed electron acceptor methyl viologen (MV$^{2+}$), combining aspects and approaches cited in the previous paragraph. The aim of this work was to design a system where AAET can be observed directly. In light of differences in the QD structure and composition of previous comparable studies, we have determined the intrinsic ET rate $k_{ET}$ according to the measured average number of ET-active MV$^{2+}$ per QD. A decay factor $\beta$ of 0.13 Å$^{-1}$ is obtained for CdS shell thicknesses up to 19 Å. We show the dependence of the 1Se population dynamics at short delay times on the CdS shell thickness in QDs, as a result of shell-modulated electron confinement. With small CdSe cores allowing a clear spectral separation between the 1S$_{3/2}$ and 2S$_{3/2}$ hole states ($\sim$110 meV), we have compared the ET dynamics of the 1Se electron coupled with these two hole states and have observed a slower ET rate from the 1S$_{3/2}$2S$_{3/2}$ state than the 1S$_{1/2}$1S$_{1/2}$ state with thin CdS shell. We ascribe the slower ET rate to an AAET process, which is controlled by the capping CdS shell.

2 Experimental section

2.1 QD and QD–MV$^{2+}$ sample preparation

CdSe cores of various sizes were synthesised by injecting trioctylphosphine-Se into a heated solution of cadmium phosphonate in trioctylphosphine oxide following the procedure reported by Carbone and co-workers.\textsuperscript{22}

CdSe/CdS core/shell QDs were synthesised as reported in a previous work.\textsuperscript{14} Cadmium oleate (0.168 M in octadecene) was used as the cadmium source and octane-thiol as the sulphur source. The required amount of each precursor for a five-monolayer CdS shell was determined using the technique described by ref. 12 and diluted with ODE to a total volume of 7.5 mL. The solutions were then loaded into separate syringes and loaded into a syringe pump.

Separately, octadecene (3 mL), oleylamine (3 mL) and 100 nmol of purified CdSe QDs (dispersed in hexane) were added to a 50 mL round-bottom flask equipped with a magnetic stirrer. The solution was held at 50 °C under vacuum (<1 mbar) for one hour, heated to 120 °C for a further 15 minutes, then placed under nitrogen and heated to 310 °C. Once the solution had reached 230 °C injection of both precursors was initiated at a rate of 3 mL per hour, corresponding to a shell growth rate of 2 monolayers per hour. Samples of 1 and 3 monolayer thickness were isolated by halting the syringe pumps after the appropriate volume of precursor had been added, cooling to 100 °C and removing one-third and one-half of the reaction solution volume, respectively. The removed fractions were mixed with 0.33 mL oleic acid and washed. The remaining reaction solution was re-heated to 310 °C with resumption of precursor injection at 230 °C. The precursor addition rate was dropped by a factor of one-third after each removal to account for the reduction in the number of QDs. After the final 5 monolayer shell thickness was achieved the remaining reaction solution was allowed to cool to room temperature and mixed with 0.33 mL oleic acid.

Each sample was washed three times via precipitation with acetone, centrifugation, and redispersion in chloroform. After the final wash the particles were redispersed in hexane and passed through a 0.2 micron PTFE filter.

By applying the above procedure, we prepared CdSe/CdS core/shell QDs with 1.2, 3.7 and 5.7 monolayers of the CdS shell. Actual shell thicknesses were measured using TEM (200 keV Technai TF-20) as shown in Fig. S1.\textsuperscript{†} They were close to those predicted from shell growth calculations. The CdSe core possesses an average diameter of 4.84 ± 0.28 nm and the thickness of one monolayer (ML) of CdS shell has been determined to be 3.4 Å. The average CdS shell thicknesses of the three batches are 4.1 Å (1.2 MLs), 12.6 Å (3.7 MLs) and 19.4 Å (5.7 MLs) for each batch of CdSe/CdS QDs, respectively.

Three batches of QDs (~1.8 nmol of each) were diluted with chloroform to a total volume of 600 µL, respectively. Thus the concentrations of all QD solutions were 3 µM. We prepared the QD–MV$^{2+}$ complex solution by adding MV$^{2+}$ dissolved in methanol (1 mM) into the QD solution step by step after each TA measurement. The molar ratio between added MV$^{2+}$ and QDs was varied from 0 to 50. A test-tube vibrator was applied before each TA measurement to allow MV$^{2+}$ to bind to the QDs homogeneously.

2.2 Femtosecond transient absorption spectroscopy

A high repetition rate titanium:sapphire regenerative amplifier system (Coherent RegA9050, centred at ~800 nm, 1 W and 92 kHz) was employed as the laser source. The output of the RegA amplifier was re-compressed (Coherent EC9150) to ~60 fs before being split to generate pump and probe pulses. A branch of the output was focused onto a second harmonic generation (beta barium borate (BBO)) crystal to produce 400 nm pump pulses typically of a few tens of nJ per pulse. Visible white light probe pulses were generated by focusing a small amount of the fundamental pulses (800 nm) into a 3 mm-thick sapphire substrate (Crystal Systems). A notch filter was used to block the fundamental pulse in the probe beam. Pump and probe pulses were weakly focused and overlapped at the sample with an off-axis parabolic mirror with pump spot size of 200 µm in diameter. The pump beam was mechanically chopped at, and synchronized to, a twentieth of the amplifier pulse repetition rate (4.6 kHz). The time-resolved transient absorption spectra were recorded using a high-speed fibre-optically-coupled CMOS spectrometer (Ultrafast Systems), operating at twice the modulation rate (9200 spectra per s) to sample the transmission changes of the probe beam by
comparing adjacent probe pulses with and without pump pulses, synchronized to the chopper. The delay between pump and probe pulses was controlled using a motorized delay stage (Newport UTM-PP0.1, with step size of 0.66 fs and range of 800 ps). The instrument response function of the entire setup was estimated at 200 fs (FWHM) by measuring auto-correlation of fundamental pulses. A low noise level was achieved for absorption changes of below $5 \times 10^{-5}$ OD, by taking advantage of the high-repetition-rate laser and high signal averaging approach coupled with an acquisition process that rejected any outlying spectra.²³

Samples were studied in a 2 mm-path-length cuvette, following excitation with 400 nm pump pulses, with moderated pulse energy of less than 30 nJ in order to eliminate any multi-exciton effects (see ESI†). A small magnetic stirrer was used to reduce photo-degradation and thermal effects. All measurements were performed at room temperature.

3 Results and discussion

3.1 Steady-state absorption spectroscopy

The steady state absorption (normalized to the band-edge absorption peak) and photoluminescence (PL) spectra of the CdSe/CdS core/shell structure QDs studied here are shown in Fig. 1. The two lowest energy peaks in the absorption spectrum are assigned to the 1S,1S₂ and 1S,2S₂ states, respectively.²⁴ The band-edge states 1S,1S₂ are located at 591, 604 and 616 nm, and the neighbouring 1S,2S₂ state, at 560, 570 and 585 nm for the CdSe cores with 1.2, 3.7 and 5.7 monolayer CdS shells, respectively. PL peaks exhibit a red-shift with increasing shell thickness (600 nm, 616 nm and 630 nm). The leakage of the 1S₂ electron wavefunction into the CdS shell accounts for the red-shift of both the 1S,1S₂ and 1S,2S₂ exciton states and emission peaks following the growth of the CdS shell. The PL quantum yield (QY) is improved from 24% to 54% as a result of surface passivation with thicker CdS shells.²⁵

The use of small core QDs, thereby increasing the wavefunction energies, allows for clear distinction of these two states separated by 110 meV, which was not the case in the work of Dworak et al.,²⁷ but was achieved in the work of Liu et al.²⁴ The increasing absorbance in the blue (<550 nm) with increasing CdS shelling is due to the large extinction coefficient of CdS in this spectral region.¹²

3.2 Femtosecond transient absorption spectroscopy

Fig. 2a–c show TA spectra at different delay times up to 700 ps after 400 nm excitation of different core/shell QDs in the absence and presence of MV₂⁺. All samples were excited with the average number of excitons per particle far less than 1 (see ESI†). Electrons and holes are promoted to hot energy levels, and relax to the band-edge level, giving rise to the 1S, bleaching peaks.

In Fig. 2a–c, bleaching peaks assigned to the 1S,1S₂ and 1S,2S₂ states are clearly distinguished²⁷–²⁹ and all three samples have an energy difference greater than ~110 meV between the two states. A contribution of the 2S₂ holes to the 1S,2S₂ bleaching kinetics may complicate the interpretation. The energy of hot holes dissipates quickly, within tens of picoseconds, due to the high hole state density.²⁴,³⁰,³¹ At long delay times, the bleaching of the 1S,2S₂ state is consequently dominated by the state-filling effect of 1S electrons, which is expected to resemble the bleaching at 1S,1S₂.²⁰,³² Fig. 3 compares the measured bleaching kinetics from the 1S,1S₂ and 1S,2S₂ states in CdSe/1.2CdS QDs (see ESI† for CdSe/3.7CdS and CdSe/5.7CdS). The 1S,1S₂ and 1S,2S₂ states exhibit identical decay kinetics as expected at long times. Hot hole relaxation from 2S₂ to 1S₂ is revealed by a faster decay behaviour in the 2S₂ state within the initial 100 ps. Fig. 3(b) shows the 2S₂ hole transition dynamics extracted from normalized 2S₂ and 1S₂ bleach dynamics. A single exponential fitting gives a decay time constant of 30 ps. Here we ascribe the observed 2S₂→1S₂ hole relaxation to a channel coupled to emission of LO phonons, which involves slow relaxation from 1 ps to tens of ps.²⁴,³³

The time-resolved bleaching kinetics (Fig. 2d–f) were extracted from the TA spectra of Fig. 2a–c. Multiexponential functions were applied to fit the decay kinetics in the QDs and the results are summarized in Table 1. For QDs in the absence of MV₂⁺, the time traces all exhibit a dominant slow-decaying component (the exact time constants of the slow components from the fitting are not shown because they are far beyond our delay time window), which is attributed to the relaxation of electrons to the ground state, predominantly through radiative pathways.³⁴ The fast component of the 1S,1S₂ state is suppressed by growth of the CdS shell. We ascribe this fast
relaxation process to electrons being trapped at surface defects.\textsuperscript{32,35} Capping with 5.7 MLs of CdS shell eliminates the fast relaxation component as the surfaces of the CdSe cores are well passivated by the thick shell.

The population dynamics of the 1Se electron were also investigated at short delay times. Fig. 4 shows the build-up kinetics of the 1Se\textsubscript{1S\textsubscript{3/2}} bleach signal, which is attributed to the re-population of the 1Se states after excitation. The change in population is fast and shows a decreasing rate of change (from 300 to 700 fs) with increasing CdS shell thickness. This is in contrast to what might be expected for a phonon-assisted transition, which occurs slowly between the energy levels separated by a large energy gap in QDs with thin CdS shells. Klimov et al. attributed these abnormal trends to an ultrafast Auger-assisted 1P\textsubscript{y}-to-1S\textsubscript{e} transition,\textsuperscript{36} which involves a confinement-enhanced electron relaxation process bypassing the phonon-bottleneck effect. The observed dependence of the build-up kinetics on the shell thickness can be interpreted in terms of the weak confinement of electrons in the presence of the thick CdS shell.

The TA spectra (see Fig. 2a–c), in the presence of MV\textsuperscript{2+}, present the same features but different time-dependent trends to those observed in the absence of MV\textsuperscript{2+}. In the presence of MV\textsuperscript{2+}, clear red-shifts of the bleach peaks are observed in each sample during the measurement time window of 700 ps. This may be due to a Stark-shift of the exciton bands in the charge separated states.\textsuperscript{37,38}

MV\textsuperscript{+} has a broad absorption band above 600 nm that can potentially complicate interpretation of TA spectra. Electron transfer from QDs to MV\textsuperscript{2+} leads to the formation of MV\textsuperscript{+} cations, which will contribute to the TA signals in a range overlapping the 1Se bleach of QDs. Fig. S3\textsuperscript{†} shows TA signals in QDs and QD–MV\textsuperscript{2+} complexes in a wavelength range between 600 and 700 nm. The contribution of MV\textsuperscript{+} to TA signals is negligible due to the small \( <N_{\text{ex}}> \) we excited, indicating a good approximation of our analysis on TA signals of QDs. We could also give an estimation of TA signals arising from MV\textsuperscript{+}. The maximum extinction coefficient of MV\textsuperscript{+} is 13 900 M\textsuperscript{–1} cm\textsuperscript{–1} at \( \lambda_{\text{max}} = 606 \text{ nm} \).\textsuperscript{39} Given that QD = 3 \( \mu \)M, \( <N_{\text{ex}}> = 0.1 \), and pathlength = 2 mm, the greatest change of TA signals with an addition of MV\textsuperscript{+} is less than 0.8 mOD, which is far less than that at the 1Se bleach peaks we investigated (>10 mOD).

The QD–MV\textsuperscript{2+} complexes show a markedly faster decay than the QDs, due to the ET channel from the QDs to the adsorbed MV\textsuperscript{2+} radicals (see Fig. 2d–f). Furthermore, the TA kinetics of 1Se in all three batches of QD–MV\textsuperscript{2+} complexes exhibit faster decays with increasing concentrations of MV\textsuperscript{2+}.  

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**Fig. 2** (a–c): TA spectra of CdSe/CdS QDs (top) and QD–MV\textsuperscript{2+} complexes (bottom) at different delay times after 400 nm excitation. Bleaching peaks are assigned to different exciton states indicated by color blocks in each panel (red: 1S\textsubscript{e}1S\textsubscript{3/2}; blue: 1S\textsubscript{e}2S\textsubscript{3/2}). (d–f): normalized bleaching kinetics of 1S\textsubscript{e}1S\textsubscript{3/2} (bottom, red) and 1S\textsubscript{e}2S\textsubscript{3/2} (top, blue) state in three batches of QDs (solid lines) and QD–MV\textsuperscript{2+} complexes (dashed lines and filled areas) within 700 ps. The concentrations of all QD solutions were 3 \( \mu \)M and the number of added MV\textsuperscript{2+} per QD was 10 for all QD–MV\textsuperscript{2+} samples. The excitation power was kept low for all measurements in order to avoid multi-exciton effect (see ESI†).
This concentration dependence is ascribed to the multiple ET pathways when multiple ET-active MV$_2^+$ moieties are associated with each QD. Following the work of Morris-Cohen et al.,$^{21}$ we calculated the intrinsic ET rate $k_{ET}$, which is the rate of electron transfer for only one ET-active MV$_2^+$ radical per QD. The observed ET rate $k_{ET,obs}$ is assumed to equal $nk_{ET}$,$^{40}$ where $n$ is the number of ET-active MV$_2^+$ binding to one QD. With an assumption of a Poisson distribution of QD–MV$_2^+$ binding,$^{41-43}$ the probability $f(n)$, of QDs with $n$ absorbed MV$_2^+$ radicals is given by:

$$f(n) = \frac{\lambda^n e^{-\lambda}}{n!}$$  \hspace{1cm} (1)

where $\lambda$ is the average number of ET-active MV$_2^+$ radicals per QD. In order to obtain the intrinsic ET rate, it is crucial to accurately determine $\lambda$, which is expected to be smaller than the amount of added MV$_2^+$ per QD, because not all added viologen molecules will adsorb to the QDs. The value for $\lambda$ was determined from the ratio between the TA bleach signal for QDs without MV$_2^+$, $B_0$, and that in the QD–MV$_2^+$ complex, $B$ (see ESI†),$^{21}$ given by:

$$\lambda = -\ln(B/B_0)$$  \hspace{1cm} (2)

Fig. 5 shows $\lambda$ as a function of concentration of added free MV$_2^+$ in the QD–MV$_2^+$ complex solutions. Fitting the data using a Langmuir isotherm model:

$$\lambda = \lambda_{max} \frac{K_a [MV_2^+]_{free}}{1 + K_a [MV_2^+]_{free}}$$  \hspace{1cm} (3)

Table 1 Decays time constants $r_i$ and corresponding amplitudes $A_i$ from fitting of TA bleaching decay kinetics in QDs as shown in Fig. 2d–f by a multieponential model

<table>
<thead>
<tr>
<th>Monolayer</th>
<th>Energy level</th>
<th>$r_1$ ($A_1$)</th>
<th>$r_2$ ($A_2$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.2 MLs</td>
<td>1S, 1S$_{3/2}$</td>
<td>76 ps (0.1)</td>
<td>$&gt;1$ ns (0.9)</td>
</tr>
<tr>
<td></td>
<td>1S$_{3/2}$</td>
<td>52 ps (0.1)</td>
<td>$&gt;1$ ns (0.9)</td>
</tr>
<tr>
<td>3.7 MLs</td>
<td>1S, 1S$_{3/2}$</td>
<td>99 ps (0.1)</td>
<td>$&gt;1$ ns (0.9)</td>
</tr>
<tr>
<td></td>
<td>1S$_{3/2}$</td>
<td>77 ps (0.2)</td>
<td>$&gt;1$ ns (0.8)</td>
</tr>
<tr>
<td>5.7 MLs</td>
<td>1S, 1S$_{3/2}$</td>
<td>—</td>
<td>$&gt;1$ ns (1)</td>
</tr>
<tr>
<td></td>
<td>1S$_{3/2}$</td>
<td>108 ps (0.1)</td>
<td>$&gt;1$ ns (0.9)</td>
</tr>
</tbody>
</table>

(see ESI†). This concentration dependence is ascribed to the multiple ET pathways when multiple ET-active MV$_2^+$ moieties are associated with each QD. Following the work of Morris-Cohen et al.,$^{21}$ we calculated the intrinsic ET rate $k_{ET}$, which is the rate of electron transfer for only one ET-active MV$_2^+$ radical per QD. The observed ET rate $k_{ET,obs}$ is assumed to equal $nk_{ET}$,$^{40}$ where $n$ is the number of ET-active MV$_2^+$ binding to one QD. With an assumption of a Poisson distribution of QD–MV$_2^+$ binding,$^{41-43}$ the probability $f(n)$, of QDs with $n$ absorbed MV$_2^+$ radicals is given by:

$$f(n) = \frac{\lambda^n e^{-\lambda}}{n!}$$  \hspace{1cm} (1)

where $\lambda$ is the average number of ET-active MV$_2^+$ radicals per QD. In order to obtain the intrinsic ET rate, it is crucial to

$$\lambda = \lambda_{max} \frac{K_a [MV_2^+]_{free}}{1 + K_a [MV_2^+]_{free}}$$  \hspace{1cm} (3)

where $\lambda$ is the average number of ET-active MV$_2^+$ radicals per QD. In order to obtain the intrinsic ET rate, it is crucial to...
yields maximum average numbers of ET-active MV$^{2+}$ per QD of $\lambda_{\text{max}} = 3.94 \pm 0.22$, $2.53 \pm 0.11$, and $1.23 \pm 0.04$ for 1.2, 3.7 and 5.7 MLs of the CdS shell respectively. We ascribe the dependence of $\lambda_{\text{max}}$ on the shell thickness to a decrease in available surface binding sites. Weiss and co-workers$^{44}$ reported a comparable reduction in the fractional surface coverage of ligands on the QD $\lambda_{\text{max}}$ in QD-ligand solutions as the QD concentration was increased, which they interpreted in terms of aggregation of the QDs. However, there was no spectroscopically perceptible aggregation in the systems used here. We therefore attribute this dependence of the available surface binding sites to effects of the shell (thickness and/or surface properties).

Applying an infinite sum of exponentials to fit the measured TA bleaching decay, and combining eqn (1) of the Poisson distribution, the intrinsic ET rate $k_{\text{ET}}$ is derived as (see ESI†):

$$k_{\text{ET}} = -\frac{1}{\tau_{1/2}} \ln \left[ 1 - \frac{\ln (2g(\tau_{1/2}))}{\lambda} \right]$$  \hspace{1cm} (4)

where $\tau_{1/2}$ is the measured duration taken to reach half the initial maximum bleaching intensity in the QD–MV$^{2+}$ complexes and $g(t)$ is the measured bleaching decay in QDs without MV$^{2+}$. The values of $k_{\text{ET}}$ from the 1Se1S$_{3/2}$ and 1Se$_2$S$_{3/2}$ states are plotted in Fig. 6 as a function of the concentration of the added MV$^{2+}$ per QD. The intrinsic ET rates are constant for all samples as expected and are summarised in Table 2.

The values obtained lie in the range $10^8$–$10^{10}$ s$^{-1}$ in good agreement with recent published results for other QD-acceptor pairs.$^{17,18,21,45}$ Fig. 7 shows an exponential fit $k_{\text{ET}} = k_0 e^{-\beta t}$, to the measured intrinsic ET rate $k_{\text{ET}}$ from 1Se1S$_{3/2}$ with varying shell thickness $t$, yielding an attenuation factor $\beta$ of 0.13 ± 0.05 Å$^{-1}$. The error indicates the 95% confidence interval of the fitting parameters given by the fitting method.

The value of $\beta$ we obtained in the CdSe/CdS–MV$^{2+}$ complexes studied here is significantly lower than results published recently by Dworak$^{7}$ et al. for a related system. They reported a value of $\beta = 0.33$ Å$^{-1}$ for CdSe/CdS–MV$^{2+}$ complexes with larger CdSe cores (6.1 nm in diameter) capped with thinner 1.75–5.25 Å-thick CdS shells. Hines et al. obtained a smaller value of $\beta = 0.08$ Å$^{-1}$ in CdSe/TiO$_2$ bridged by organic molecules with an increasing length from 3 to 21 Å.$^{45}$ Importantly, we have determined the actual number of ET-active MV$^{2+}$ acceptor molecules on the QDs and used this number in the calculation of the intrinsic ET rates, instead of using the number of added MV$^{2+}$ that was assumed in Dworak’s work. As discussed above (see Fig. 5), the actual number of ET-active MV$^{2+}$ molecules per QD drops as the thickness of the shell increases in the QD–MV$^{2+}$ complexes (for identical added acceptor molecule concentrations), thereby leading to an observed faster ET rate.

According to the Marcus–Hush model for ET$^{46,47}$

$$k_{\text{ET}}(R) = \frac{2\pi}{\hbar} \left| H(R) \right|^2 \frac{1}{\sqrt{4k_B T}} \exp \left[ -\frac{\left( \lambda_R + \Delta G \right)^2}{4k_B T} \right]$$  \hspace{1cm} (5)

where $\Delta G$ is the change in the Gibbs free energy, $\lambda_R$ is the reorganisation energy of the complex system, $R$ is the electron
donor-to-acceptor distance, and \(|H(R)|^2\) describes the wavefunction overlap between the electron level and the molecular orbital of the adsorbed acceptors. Based on this model, the inorganic shell affects the ET process via three distinct mechanisms: (i) by separating the adsorbed electron acceptors away from the QDs in space;\(^{15}\) (ii) by serving as a tunnelling barrier that slows the electron transfer;\(^{48}\) and (iii) by directly modifying the excited state carrier wavefunction.\(^{17}\) In the three batches of CdSe/CdS QDs studied here, the energy levels are marginally affected by the CdS shell, as indicated by the red shift of \(\sim 85\) meV of the band-edge absorption peak from 1.2 to 1.7 MLs (see Fig. 1). Comparing this to the estimated value for \(\Delta G\) of 0.4–1 eV (ref. 16–18) suggests that the contribution due to mechanism (iii) is negligible.

In order to estimate the effect of mechanism (ii), we consider the electron wavefunction overlap \(|H(R)|^2\) and assume that it is proportional to the electron density \(|\Psi(R)|^2\) at the QD–acceptor interface, i.e. the electron transfer rate \(k_{ET} \propto |\Psi(R)|^2\). We extract relative values of \(|\Psi(R)|^2\) at the surface of the QDs from the simulation results, as shown in Fig. S5 and S6.\(^{†}\) An exponential fitting to the scaled \(|\Psi(R)|^2\) with the CdS shell thickness yields a decay factor \(\beta\) of 0.18 Å\(^{-1}\), which is in good agreement with the measured decay constant.

In using the widely-applied ET model discussed above, it is generally assumed that the \(1S_e\) ET dynamics are independent of the hole energy, however, as indicated in Fig. 7 inset, a noticeably slower ET rate \(k_{ET}^{1S_e} = 2.52 \times 10^{10}\) s\(^{-1}\) compared to \(k_{ET}^{1S_J} = 3.52 \times 10^{10}\) s\(^{-1}\) is found in the case of the CdSe core capped with 1.2 MLs of the CdS shell, whereas for the 3.7 and 5.7 ML the rates are essentially identical in each case (see Table 2). This observation is in contrast to what one may expect: the two \(1S_e\) ET rates should be identical regardless of the hole state, indeed the rates from the two states in CdSe/3.7CdS and CdSe/5.7CdS are very similar. Lian and co-workers have recently proposed the existence of an additional, Auger-assisted electron transfer (AAET) channel,\(^{18}\) in which the ET is coupled to excitation of the hole. Here we first interpret the slower rate \(k_{ET}^{1S_e}\) by considering a lack of Auger-assisted \(1S_{J/2}\) to \(2S_{J/2}\) or higher hole transitions coupled to the electron transfer at short time scales. As shown in Fig. 8, for the \(1S_e1S_{J/2}\) state, the electron transfer to the \(MV^{2+}\) is accompanied by the hole becoming excited to higher levels via the Auger process. At short time scales before the \(2S_{J/2}\) hole relaxes to the lowest state, the Auger process cannot occur, resulting in slower transfer rates. According to Zhu, the AAET is given by:\(^{16}\)

\[
k_{ET} \propto \int_0^\infty dE_h E_h \exp \left[ -\frac{(E_h + \Delta G + E_h)^2}{4k_BT} \right] \tag{6}
\]

where \(E_h\) is the hole energy in a quasi-continuum of valence band levels. It is easy to qualitatively infer that the ET rate becomes slower in the absence of the Auger-assisted \(1S_{J/2}\) to \(2S_{J/2}\) transition. Hyeon-Deuk et al. simulated the AAET process and confirmed that there should be a slower ET rate in the absence of the Auger process.\(^{19}\)

Cds shells could affect the AAET channel by controlling electron–hole coupling in CdSe/CdS QDs. With thick Cds shells, the electron wavefunction is spread over the core/shell heterostructure while the hole wavefunction is almost confined within the core. Thus the importance of the Auger-assisted channel is reduced, due to the decreasing overlap of the electron and hole wavefunctions (see Fig. S4†). As mentioned above, the population dynamics of the \(1S_e\) state (see Fig. 4) also reflect the extent of the Auger type process induced by carrier confinement, which could be controlled by the Cds shell.

4. Conclusions

In summary, we have studied the effects of the Cds shell thickness on the dynamics of \(1S_e\) electron transfer from quasi-type II CdSe/CdS QDs to adsorbed methyl viologen cations. We have measured the number of ET-active \(MV^{2+}\) per QD with a TA-based method and determined the intrinsic ET rate. The electrons are extracted by the adsorbed \(MV^{2+}\) radicals and the ET rate decreases with increasing shell thicknesses, with an attenuator factor \(\beta\) of 0.13 Å\(^{-1}\). There is a difference in ET rates for the \(1S_e1S_{J/2}\) and \(1S_e2S_{J/2}\) states, which we attribute to an AAET process, in which the \(1S_e\) electron transfer to the viologen is accompanied by the excitation of the hole to higher levels. We have also found that the lowest \(1S_e\) state populates more slowly with increasing Cds shell as a result of weakened electron confinement. These results suggest that electron transfer and Auger relaxation processes can be tailored in these systems by optimising the shell thickness.
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